

GaAs QFN 5x5mm Drive Amplifier 2-20GHz

Features

- Single Biasing Voltage (Self Biased)
- Frequency: 2-20GHz
- Small Signal Gain: 12.5dB Typical
- Gain Flatness: \pm 1.0dB Typical
- Noise Figure:4.5dB Typical
- P1dB: 24dBm Typical
- Psat: 25dBm Typical
- Supply voltage: +8V/185mA
- Input/Output: 50Ω
- Package Size : 5 x 5x 1mm

Typical Applications

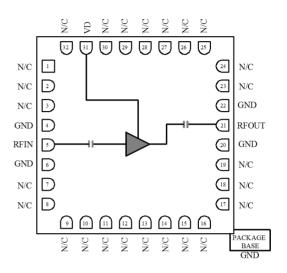
- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

Electrical Specifications

TA = +25°C, VD = +8V, IDD = 185mA Typical

Parameters	Min.	Тур.	Max.	Units
Frequency	2-20			GHz
Small Signal Gain	10	10 12.5		
Gain Flatness	±1.0		dB	
Noise Figure		5.0		dB
P1dB - Output 1dB Compression	21.5	24		dBm
Psat - Saturated Output Power	22.5	25		dBm
OIP3 - Output Third Order Intercept		33		dBm
Input Return Loss	15 d		dB	
Output Return Loss	Return Loss 18 dE		dB	

Functional Block Diagram



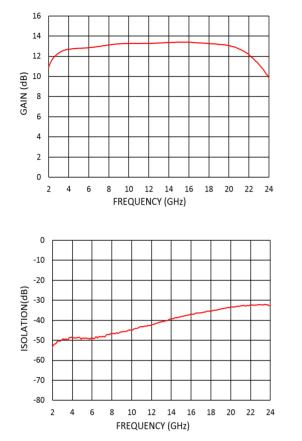


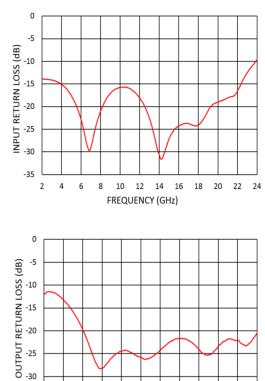
GaAs QFN 5x5mm **Drive Amplifier 2-20GHz**

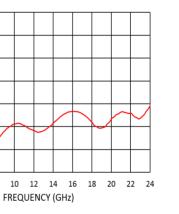
Measurement Plots: S-parameters

-35

2 4 6 8









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Absolute Maximum Ratings

Drain Bias Voltage (VD)	+10V
RF Input Power (RFIN)	+20dBm
Channel Temperature	175°C
Continuous Pdiss (T = 85 °C) (derate 22mW/°C above 85 °C)	2W
Thermal Resistance (channel to die bottom)	50°C/W
Operating Temperature	-55°C to +85 °C
Storage Temperature	-65°C to +150°C

Typical Supply Current vs. VD

VD (V)	IDD (mA)	
8	185	

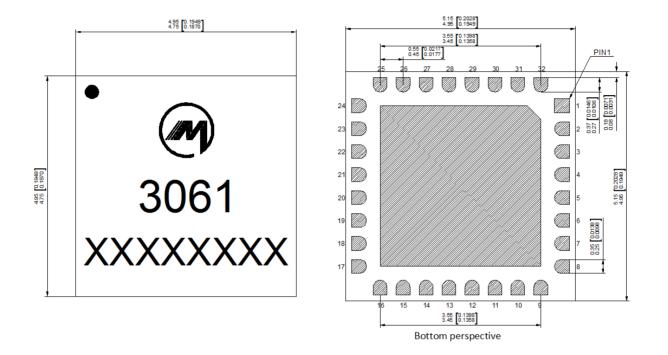


ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS MM3061Q5A



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Outline Drawing: All Dimensions in mm[inches]





Notes:

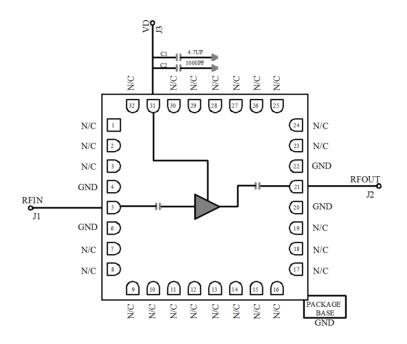
- **1.** Package body material : Alumina.
- 2. Lead and ground paddle plating: Gold flash over nickel.
- 3. Dimensions are in millimeters(inches).
- 4. Lead spacing tolerance is non-cumulative.

MM3061Q5A



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Assembly Drawing

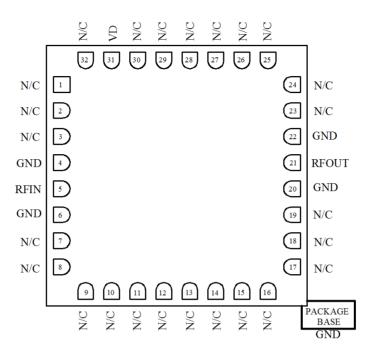


Pin Descriptions

No	Function	Description
1,2,3,7,8,9,10,11,12,13,14, 15,16,17,18,19,23,24,25,26 ,27,28,29,30,32	NC	No connection. These pins may be connected to RF ground. Performance will not be affected.
5	RF IN	RF Signal Input. This pad is dc-coupled and matched to 50 $\boldsymbol{\Omega}.$
21	RF OUT	RF Signal Output. This pad is dc-coupled and matched to 50 Ω .
31	VD	Connect to external 1000pf and 4.7uf bypass capacitors.
4,6,20,22	GND	These pins & exposed ground paddle must be connected to RF/DC ground
	GND	Package bottom must be connected to RF/DC ground



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Biasing and Operation

Turn ON procedure:

- 1. Connect GND to RF and dc ground.
- 2. Apply positive drain voltage VD and set to +8.0 V.
- 3. Apply RF signal.

Turn OFF procedure:

- 1. Turn off the RF signal.
- 2. Turn off the positive drain voltage VD.

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